

ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

PRODUCT APPLICATIONS

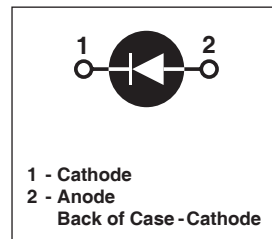
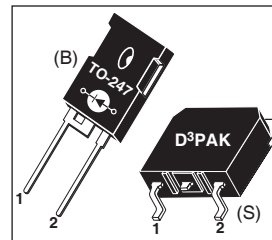
- Anti-Parallel Diode
 - Switchmode Power Supply
 - Inverters
- Free Wheeling Diode
 - Motor Controllers
 - Converters
 - Inverters
- Snubber Diode
- PFC

PRODUCT FEATURES

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- Popular TO-247 Package or Surface Mount D³PAK Package
- Low Forward Voltage
- Low Leakage Current
- Avalanche Energy Rated

PRODUCT BENEFITS

- Low Losses
- Low Noise Switching
- Cooler Operation
- Higher Reliability Systems
- Increased System Power Density



MAXIMUM RATINGS

All Ratings: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT75DQ60B(G)_S(G)	UNIT
V_R	Maximum D.C. Reverse Voltage	600	Volts
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		
V_{RWM}	Maximum Working Peak Reverse Voltage		
$I_{F(AV)}$	Maximum Average Forward Current ($T_C = 108^\circ\text{C}$, Duty Cycle = 0.5)	75	Amps
$I_{F(RMS)}$	RMS Forward Current (Square wave, 50% duty)	117	
I_{FSM}	Non-Repetitive Forward Surge Current ($T_J = 45^\circ\text{C}$, 8.3ms)	600	
E_{AVL}	Avalanche Energy (1A, 40mH)	20	mJ
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to 175	$^\circ\text{C}$
T_L	Lead Temperature for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
V_F	Forward Voltage		$I_F = 75\text{A}$	2.0	Volts
			$I_F = 150\text{A}$	2.4	
			$I_F = 75\text{A}, T_J = 125^\circ\text{C}$	1.7	
I_{RM}	Maximum Reverse Leakage Current		$V_R = 600\text{V}$	25	μA
			$V_R = 600\text{V}, T_J = 125^\circ\text{C}$	500	
C_T	Junction Capacitance, $V_R = 200\text{V}$		110		pF

DYNAMIC CHARACTERISTICS

APT75DQ60B(G)_S(G)

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
t_{rr}	Reverse Recovery Time	$I_F = 1A, di_F/dt = -100A/\mu s, V_R = 30V, T_J = 25^{\circ}C$	-	29		ns
t_{rr}	Reverse Recovery Time		-	31		
Q_{rr}	Reverse Recovery Charge	$I_F = 75A, di_F/dt = -200A/\mu s, V_R = 400V, T_C = 25^{\circ}C$	-	55		nC
I_{RRM}	Maximum Reverse Recovery Current		-	4	-	Amps
t_{rr}	Reverse Recovery Time	$I_F = 75A, di_F/dt = -200A/\mu s, V_R = 400V, T_C = 125^{\circ}C$	-	140		ns
Q_{rr}	Reverse Recovery Charge		-	650		nC
I_{RRM}	Maximum Reverse Recovery Current		-	9	-	Amps
t_{rr}	Reverse Recovery Time	$I_F = 75A, di_F/dt = -1000A/\mu s, V_R = 400V, T_C = 125^{\circ}C$	-	90		ns
Q_{rr}	Reverse Recovery Charge		-	1300		nC
I_{RRM}	Maximum Reverse Recovery Current		-	27		Amps

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			.34	$^{\circ}C/W$
W_T	Package Weight		0.22		oz
			5.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

APT Reserves the right to change, without notice, the specifications and information contained herein.

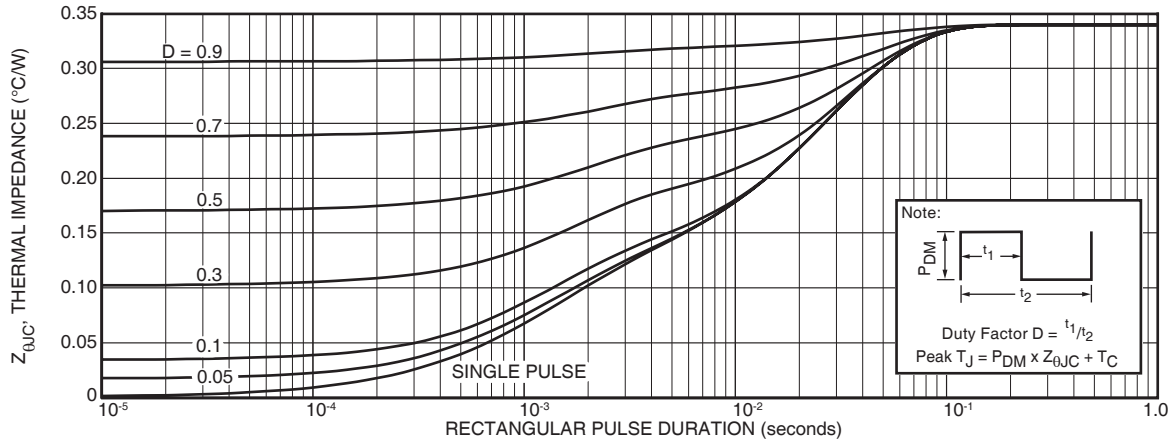


FIGURE 1a. MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

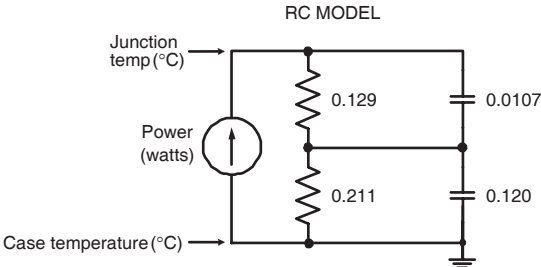


FIGURE 1b. TRANSIENT THERMAL IMPEDANCE MODEL

TYPICAL PERFORMANCE CURVES

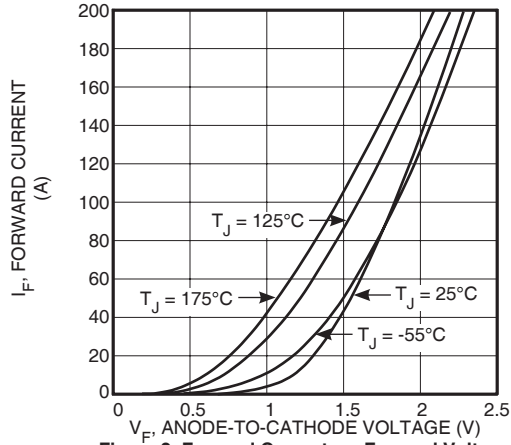


Figure 2. Forward Current vs. Forward Voltage

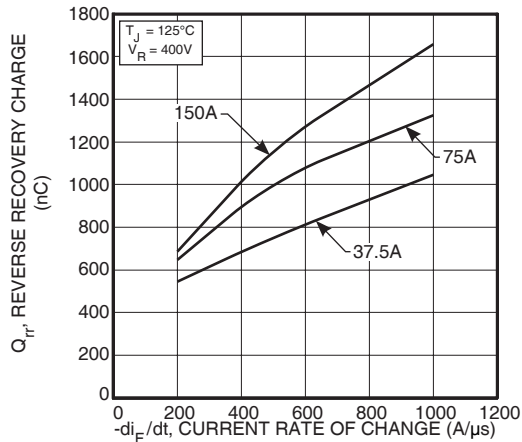


Figure 4. Reverse Recovery Charge vs. Current Rate of Change

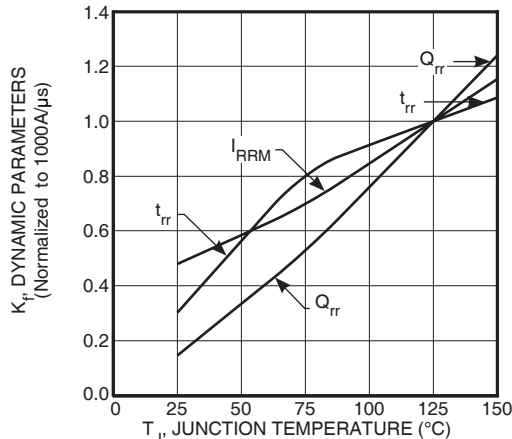


Figure 6. Dynamic Parameters vs. Junction Temperature

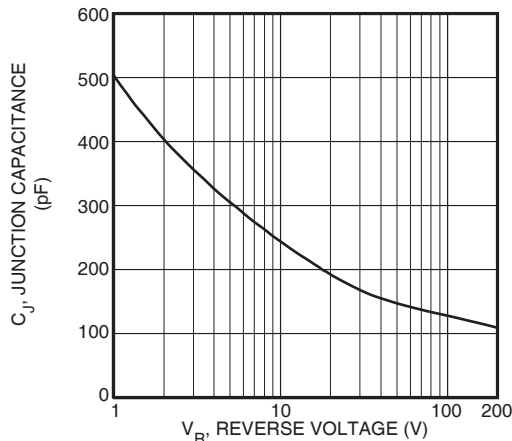


Figure 8. Junction Capacitance vs. Reverse Voltage

APT75DQ60B(G)_S(G)

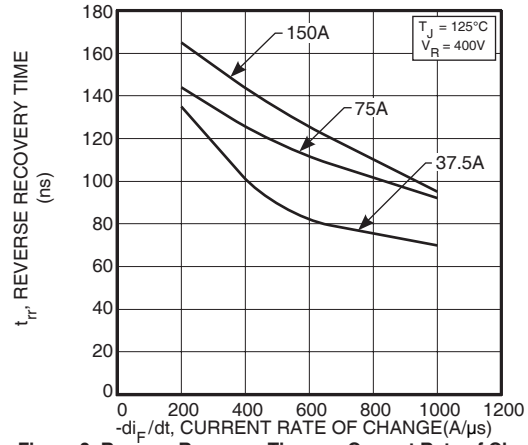


Figure 3. Reverse Recovery Time vs. Current Rate of Change

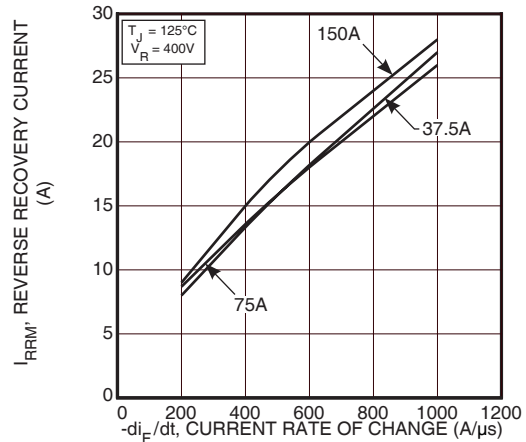


Figure 5. Reverse Recovery Current vs. Current Rate of Change

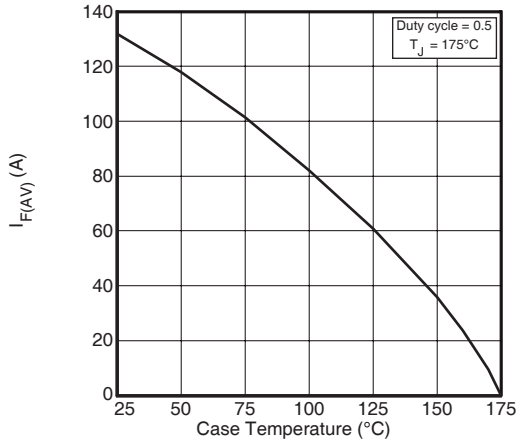
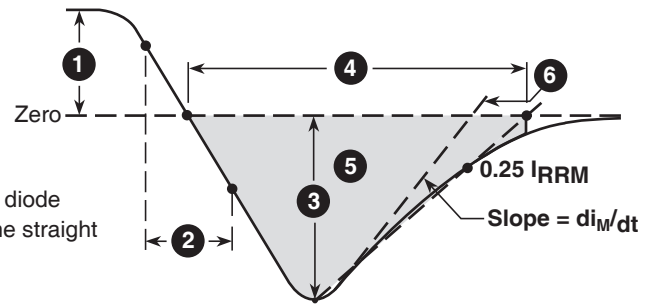


Figure 7. Maximum Average Forward Current vs. Case Temperature

- 1 I_F - Forward Conduction Current
- 2 di_F/dt - Rate of Diode Current Change Through Zero Crossing.
- 3 I_{RRM} - Maximum Reverse Recovery Current.
- 4 t_{rr} - Reverse Recovery Time, measured from zero crossing where current goes from positive to negative, to the point at which line through I_{RRM} and $0.25 \cdot I_{RRM}$ passes through zero.



- 6 di_M/dt - Maximum Rate of Current Increase During the Trailing Portion of t_{rr} .

Technical drawing of the 6X4 vacuum tube, showing the pinout and dimensions. The drawing includes the following dimensions (in inches and millimeters):

- Top dimensions: 4.69 (.185), 5.31 (.209), 1.49 (.059), 2.49 (.098)
- Right dimensions: 15.49 (.610), 16.26 (.640), 5.38 (.212), 6.20 (.244), 3.50 (.138), 3.81 (.150)
- Bottom dimensions: 1.65 (.065), 2.13 (.084)
- Left dimensions: 2.21 (.087), 2.59 (.102)
- Internal dimensions: 6.15 (.242) BSC, 20.80 (.819), 21.46 (.845), 4.50 (.177) Max., 19.81 (.780), 20.32 (.800), 1.01 (.040), 1.40 (.055), 10.90 (.430) BSC

The drawing also includes labels for the **Cathode**, **Anode**, and **Cathode** (bottom right).

Figure 1: Dimensions of the Cathode (Heat Sink) and Leads

The diagram illustrates the dimensions of the Cathode (Heat Sink) and Leads. The dimensions are provided in inches and millimeters.

Top View Dimensions:

- Overall width: 15.85 (624) / 16.05 (632)
- Lead width: 1.00 (039) / 1.15 (045)
- Lead spacing: 1.90 (075) / 2.10 (083)
- Lead width (bottom): 1.20 (047) / 1.40 (055)
- Lead spacing (bottom): 2.40 (094) / 2.70 (106) (Base of Lead)
- Overall height: 18.70 (.736) / 19.10 (.752)
- Heat Sink (Cathode) and Leads are Plated

Side View Dimensions:

- Overall height: 4.90 (.193) / 5.10 (.201)
- Lead height: 1.45 (.057) / 1.60 (.063)
- Lead width: 0.40 (.016) / 0.65 (.026)
- Lead spacing: 0.020 (.001) / 0.250 (.010)
- Lead width (bottom): 2.70 (.106) / 2.90 (.114)

Bottom View Dimensions:

- Overall width: 1.15 (.045) / 1.45 (.057)
- Lead width: 5.45 (.215) BSC (2 Plcs.)
- Anode

5,262,336 6,503,786 5,256,583 4,748,103 5,283,202 5,231,474 5,434,095 5,528,058 and foreign patents. US and Foreign patents pending. All Rights Reserved.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



Как с нами связаться

Телефон: 8 (812) 309 58 32 (многоканальный)

Факс: 8 (812) 320-02-42

Электронная почта: org@eplast1.ru

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.